# **Single Unbuffered Inverter**

The NL17SZU04 is a single unbuffered inverter in a tiny footprint package. The SC–70/SC–88A occupies a very small board area. The device performs much as LCX multi–gate products in speed and drive.

- Tiny SC-70/SC-88A Package
- Source/Sink  $\pm 16$  mA at 4.5 V V<sub>CC</sub>
- Over–Voltage Tolerant Inputs and Outputs
- Pin For Pin with NC7SZU04
- Chip Complexity: FETs = L6
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation

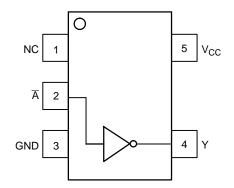


Figure 1. Pinout (Top View)

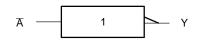


Figure 2. Logic Symbol

#### PIN ASSIGNMENT

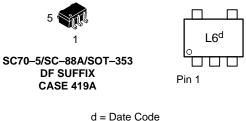
Pin	Function
1	NC
2	Ā
3	GND
4	Y
5	V <sub>CC</sub>



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#### MARKING DIAGRAMS



#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### **FUNCTION TABLE**

Input	Output Y = Ā
Α	Y
L	Н
Н	L

#### MAXIMUM RATINGS

Symbol	Parame	eter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage	-0.5 to +7.0	V	
I <sub>IK</sub>	DC Input Diode Current		-50	mA
I <sub>OK</sub>	DC Output Diode Current	-50	mA	
I <sub>OUT</sub>	DC Output Sink Current	±50	mA	
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100	mA	
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C	
TL	Lead Temperature, 1 mm from Case for 10	Seconds	260	°C
TJ	Junction Temperature Under Bias		+ 150	°C
$\theta_{JA}$	Thermal Resistance	SC-70/SC-88A (Note 1) TSOP-5	350 230	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C	SC-70/SC-88A TSOP-5	150 200	mW
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	>2000 >200 N/A	V

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum–rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A.

3. Tested to EIA/JESD22-A115-A.

4. Tested to JESD22–C101–A.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage	(Operating) Data Retention Only	1.65 1.5	5.5 5.5	V
V <sub>IN</sub>	DC Input Voltage		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage		0	5.5	V
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	$\begin{array}{l} {\sf V}_{CC} = 3.0 \; {\sf V} \; \pm 0.3 \; {\sf V} \\ {\sf V}_{CC} = 5.0 \; {\sf V} \; \pm 0.5 \; {\sf V} \end{array}$	0 0	100 20	ns/V

# DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

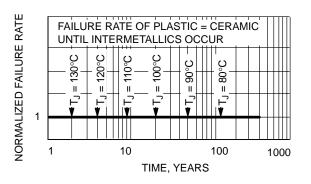


Figure 3. Failure Rate vs. Time Junction Temperature

			V <sub>CC</sub>	Τμ	ע = 25°C		<b>−40°C</b> ≤	$T_A \leq 85^\circ C$	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input Voltage		1.65 to 1.85	0.85 V <sub>CC</sub>			0.85 V <sub>CC</sub>		V
			2.3 to 5.5	0.8 V <sub>CC</sub>			0.8 V <sub>CC</sub>		
V <sub>IL</sub>	Low–Level Input Voltage		1.65 to 1.85			0.15 V <sub>CC</sub>		0.15 V <sub>CC</sub>	V
			2.3 to 5.5			0.2 V <sub>CC</sub>		0.2 V <sub>CC</sub>	
V <sub>OH</sub>	High–Level Output Voltage V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>	I <sub>OH</sub> = -100 μA I <sub>OH</sub> = -3 mA	1.65 to 5.5 1.65	V <sub>CC</sub> - 0.1 1.29	V <sub>CC</sub> 1.52		V <sub>CC</sub> - 0.1 1.29		V
		I <sub>OH</sub> = -4 mA	2.3	1.9	2.1		1.9		
		I <sub>OH</sub> = -6 mA	2.7	2.2	2.4		2.2		
		I <sub>OH</sub> = -8 mA	3.0	2.4	2.7		2.4		
		$I_{OH} = -12 \text{ mA}$	3.0	2.3	2.5		2.3		
		I <sub>OH</sub> = -16 mA	4.5	3.8	4.0		3.8		
V <sub>OL</sub>	Low–Level Output Voltage $V_{IN} = V_{IH}$ or $V_{OH}$	I <sub>OL</sub> = 100 μA I <sub>OL</sub> = 3 mA	1.65 to 5.5 1.65		0.08	0.1 0.24		0.1 0.24	V
		I <sub>OL</sub> = 4 mA	2.3		0.20	0.3		0.3	
		I <sub>OL</sub> = 6 mA	2.7		0.22	0.4		0.4	
		I <sub>OL</sub> = 8 mA	3.0		0.28	0.4		0.4	
		I <sub>OL</sub> = 12 mA	3.0		0.38	0.55		0.55	
		I <sub>OL</sub> = 16 mA	4.5		0.42	0.55		0.55	
I <sub>IN</sub>	Input Leakage Current	$V_{IN} = V_{CC}$ or GND	0 to 5.5			±0.1		±1.0	μA
I <sub>OFF</sub>	Power Off–Output Leakage Current	V <sub>OUT</sub> = 5.5 V	0			1		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	1.65 to 5.5			1		10	μΑ

#### DC ELECTRICAL CHARACTERISTICS

#### AC ELECTRICAL CHARACTERISTICS $t_R = t_F = 3.0 \text{ ns}$

			V <sub>CC</sub>	T <sub>A</sub> =	25°C	-40°C ≤ 1	Γ <sub>A</sub> ≤ 85°C	
Symbol	Parameter	Condition	(V)	Min	Max	Min	Мах	Unit
t <sub>PLH</sub>	Propagation Delay	$R_L = 1 M\Omega, C_L = 15 pF$	$1.8\pm0.15$	1.0	11.7	1.0	12.1	ns
t <sub>PHL</sub>	(Figure 4 and 5)	$R_L = 1 M\Omega, C_L = 15 pF$	$2.5\pm0.2$	0.8	6.2	0.8	6.5	
		$R_L = 1 M\Omega, C_L = 15 pF$	3.3 ± 0.3	0.5	4.5	0.5	4.8	
		$R_L = 500 \ \Omega, \ C_L = 50 \ pF$		1.0	6.0	1.0	6.5	
		$R_L = 1 M\Omega, C_L = 15 pF$	$5.0\pm0.5$	0.5	3.9	0.5	1.0	
		$R_L = 500 \ \Omega, \ C_L = 50 \ pF$		0.8	5.0	0.8	5.5	

### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	$V_{CC}$ = 5.5 V, $V_{I}$ = 0 V or $V_{CC}$	4.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance	10 MHz, $V_{CC}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CC}$	6.5	pF
	(Note 5)	10 MHz, $V_{CC}$ = 5.5 V, $V_I$ = 0 V or $V_{CC}$	10	

5.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

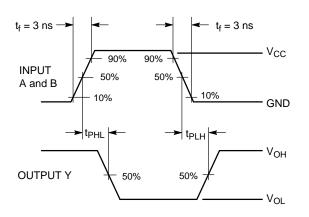
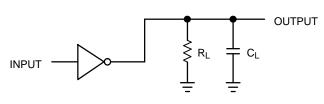


Figure 4. Switching Waveform



A 1–MHz square input wave is recommended for propagation delay tests.



### **DEVICE ORDERING INFORMATION**

	Device Nomenclature								
Device Order Number	Logic Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape and Reel Suffix	Package Type	Tape and Reel Size
NL17SZU04DFT2	NL	1	7	SZ	U04	DF	T2	SC-88A/ SOT-353/ SC70-5	178 mm, 3000 Unit

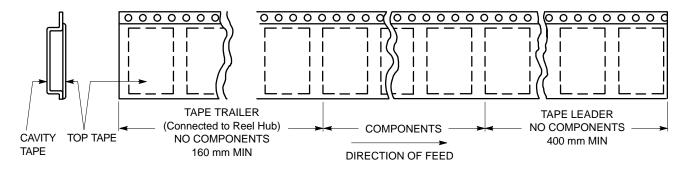


Figure 6. Tape Ends for Finished Goods

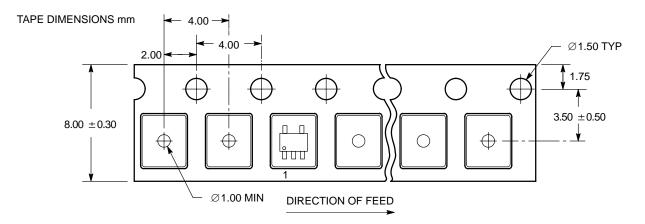
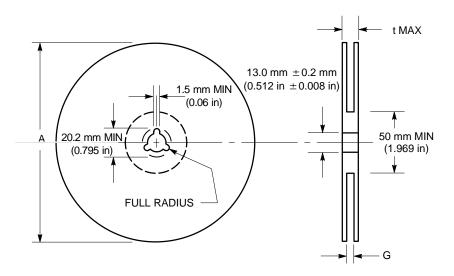


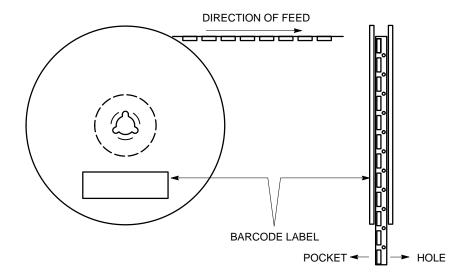
Figure 7. SC-70/SC-88A/SOT-353 DFT2 Reel Configuration/Orientation





#### **REEL DIMENSIONS**

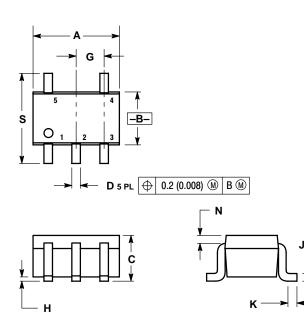
Tape Size	T and R Suffix	A Max	G	t Max
8 mm	T1, T2	178 mm (7 in)	8.4 mm, + 1.5 mm, –0.0 (0.33 in + 0.059 in, –0.00)	14.4 mm (0.56 in)





### PACKAGE DIMENSIONS

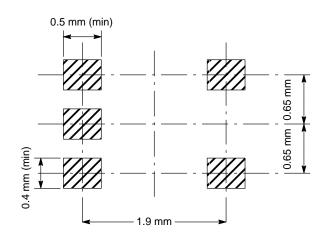
SC70-5/SC-88A/SOT-353 **DF SUFFIX** 5-LEAD PACKAGE CASE 419A-01 ISSUE F





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
ſ	0.004	0.010	0.10	0.25
Κ	0.004	0.012	0.10	0.30
Ν	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20



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